



N09/135413

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Leonard Forbes et al.

Examiner: Viet Nguyen

Serial No.: 09/135413

Group Art Unit: 2818

Filed: August 14, 1998

Docket No: 303.354US2

Title: METHOD FOR OPERATING A MEMORY DEVICE HAVING AN
AMORPHOUS SILICON CARBIDE GATE INSULATOR (as amended)

PRELIMINARY AMENDMENT

MS RCE

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Prior to taking up this application for examination, please enter the following
amendments:

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IN THE TITLE

Please amend the title as follows:

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AMORPHOUS SILICON CARBIDE GATE INSULATOR